DRCF143E

Silicon NPN epitaxial planar type

For digital circuits Complementary to DRAF143E DRC3143E in ML3 type package

■ Features

- ullet Low collector-emitter saturation voltage $V_{\text{CE(sat)}}$
- Contributes to miniaturization of sets, mount area reduction
- Eco-friendly Halogen-free package

■ Packaging

DRCF143E0L Embossed type (Thermo-compression sealing): 10000 pcs / reel (standard)

■ Absolute Maximum Ratings $T_a = 25$ °C

| Parameter | Symbol | Rating | Unit | |
|---------------------------------------|--------------------|-------------|------|--|
| Collector-base voltage (Emitter open) | V _{CBO} | 50 | V | |
| Collector-emitter voltage (Base open) | V _{CEO} | 50 | V | |
| Collector current | I _C 100 | | mA | |
| Total power dissipation | P _T | 100 | mW | |
| Junction temperature | T _j | 150 | °C | |
| Storage temperature | T _{stg} | -55 to +150 | °C | |

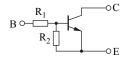
■ Package

• Code

ML3-N4-B

Package dimension clicks here. \rightarrow

- Pin Name
 - 1: Base
 - 2: Emitter
 - 3: Collector
- Marking Symbol: N5
- Internal Connection



| Resistance value | R ₁ | 4.7 | kΩ |
|------------------|----------------|-----|----|
| | R ₂ | 4.7 | kΩ |

■ Electrical Characteristics $T_a = 25$ °C±3°C

| Parameter | Symbol | Conditions | Min | Тур | Max | Unit |
|--|----------------------|--|------|-----|------|------|
| Collector-base voltage (Emitter open) | V_{CBO} | $I_C = 10 \mu A, I_E = 0$ | 50 | | | V |
| Collector-emitter voltage (Base open) | V _{CEO} | $I_C = 2 \text{ mA}, I_B = 0$ | 50 | | | V |
| Collector-base cutoff current (Emitter open) | I_{CBO} | $V_{CB} = 50 \text{ V}, I_{E} = 0$ | | | 0.1 | μΑ |
| Collector-emitter cutoff current (Base open) | I _{CEO} | $V_{CE} = 50 \text{ V}, I_{B} = 0$ | | | 0.5 | μΑ |
| Emitter-base cutoff current (Collector open) | I_{EBO} | $V_{EB} = 6 \text{ V}, I_{C} = 0$ | | | 2.0 | mA |
| Forward current transfer ratio | h_{FE} | $V_{CE} = 10 \text{ V}, I_{C} = 5 \text{ mA}$ | 20 | | | |
| Collector-emitter saturation voltage | V _{CE(sat)} | $I_C = 10 \text{ mA}, I_B = 0.5 \text{ mA}$ | | | 0.25 | V |
| Input voltage (ON) | V _{I(on)} | $V_{CE} = 0.2 \text{ V}, I_{C} = 5 \text{ mA}$ | 1.9 | | | V |
| Input voltage (OFF) | V _{I(off)} | $V_{CE} = 5 \text{ V}, I_{C} = 100 \mu\text{A}$ | | | 0.8 | V |
| Input resistance | R_1 | | -30% | 4.7 | +30% | kΩ |
| Resistance ratio | R_1/R_2 | | 0.8 | 1.0 | 1.2 | |

Note) Measuring methods are based on JAPANESE INDUSTRIAL STANDARD JIS C 7030 measuring methods for transistors.

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